



LB11891V

Three-Phase Brushless Motor Driver for Streaming Tape Drives

Overview

The LB11891V is a 3-phase brushless motor driver IC that is optimal for streaming tape drive motors and similar applications.

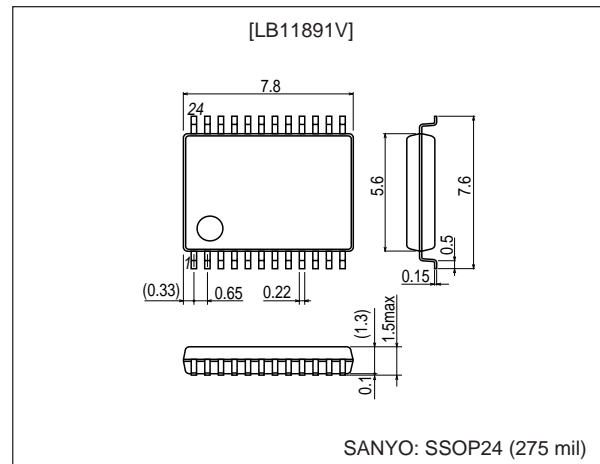
Functions and Features

- Three-phase full-wave voltage drive (120° voltage-linear drive)
- Torque ripple correction circuit (overlap correction)
- Motor supply voltage control based speed control
- Built-in Hall sensor output FG comparator
- Fixed-phase output function
- Thermal shutdown circuit

Package Dimensions

unit: mm

3175B-SSOP24



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC1} max		10	V
	V _{CC2} max		11	V
	V _S max	≤ V _{CC2}	11	V
Maximum applied output voltage	V _O max		V _S +2	V
Maximum output current	I _O max		1.0	A
Allowable power dissipation	P _d max	Independent IC	400	mW
Operating temperature	T _{opr}		-20 to +75	°C
Storage temperature	T _{stg}		-55 to +150	°C

■ Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

■ SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

SANYO Electric Co., Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

11504TN (OT) No. 7113-1/11

LB11891V

Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC1}	V _{CC1} ≤ V _{CC2}	2.7 to 6.0	V
	V _{CC2}		3.5 to 9.0	V
	VS		to V _{CC2}	V
Hall input amplitude	VHALL	Between the Hall sensor inputs	±20 to ±80	mVp-p

Electrical Characteristics at Ta = 25°C, V_{CC1} = 3 V, V_{CC2} = 4.75 V, VS = 1.5 V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[Current Drain]						
V _{CC1} Current drain	I _{CC1}	I _{OUT} = 100 mA		5.0	9.0	mA
V _{CC2} Current drain	I _{CC2}	I _{OUT} = 100 mA		7.0	10.0	mA
V _{CC1} Quiescent current	I _{CC1Q}	VSTBY = 0 V		3.0	6.0	mA
V _{CC2} Quiescent current	I _{CC2Q}	VSTBY = 0 V			100	μA
VS Quiescent current	ISQ	VSTBY = 0 V		75	100	μA
[VX1]						
High side residual voltage	VXH1	I _{OUT} = 0.2 A	0.15	0.22	0.29	V
Low side residual voltage	VXL1	I _{OUT} = 0.2 A	0.15	0.20	0.25	V
[VX2]						
High side residual voltage	VXH2	I _{OUT} = 0.5 A		0.25	0.40	V
Low side residual voltage	VXL2	I _{OUT} = 0.5 A		0.25	0.40	V
Output saturation voltage	V _{OSat}	I _{OUT} = 0.8 A, Sink + Source			1.40	V
Amount of overlap	O.L	RL = 39 Ω × 3, Rangle = 20 kΩ *1	73	80	87	%
Amount of overlap: difference between high and low sides	ΔO.L	(Average high side overlap amount) - (Average low side overlap amount) *1	-8		+8	%
[Hall Amplifiers]						
Input offset voltage	VH _{OFF}	Design target value *	-5		+5	mV
Common-mode input range	VH _{CM}	Range = 20 kΩ	0.95		2.1	V
I/O voltage gain	VG _{VH}	Range = 20 kΩ	25.5	28.5	31.5	dB
[Standby Pin]						
High-level input voltage	VSTH		2.5			V
Low-level input voltage	VSTL				0.4	V
Input current	ISTIN	VSTBY = 3 V		25	40	μA
Leakage current	ISTLK	VSTBY = 0 V			-30	μA
[FRC Pin]						
High-level input voltage	VFRCH		2.5			V
Low-level input voltage	VFRCL				0.4	V
Input current	IFRCIN	VFRC = 3 V		20	30	μA
Leakage current	IFRCLK	VFRC = 0 V			-30	μA
[VH]						
Hall supply voltage	VHALL	I _H = 5 mA, VH (+) - VH (-)	0.85	0.95	1.05	V
Minus (-) pin voltage	VH (-)	I _H = 5 mA	0.81	0.88	0.95	V

*: Design target value parameters are not tested.

Continued on next page.

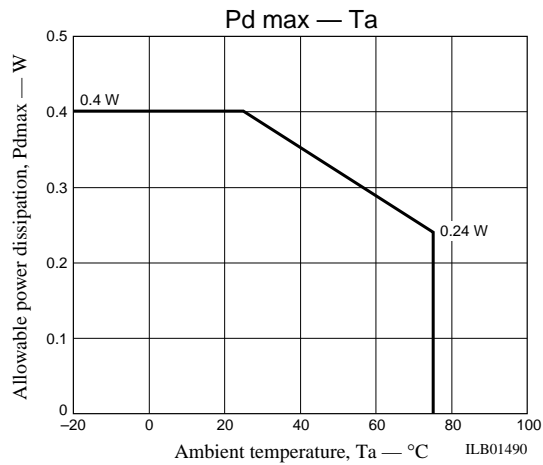
Note 1. The standard for the overlap amount parameter is to report the measured value without change.

LB11891V

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[FG Comparator]						
Input hysteresis width 1	VFGHYS1			+10		mV
Input hysteresis width 2	VFGHYS2			-10		mV
Low-level output voltage	VFGOL	When the sink current is 0.5 mA		0.2	0.4	V
High-level output voltage	VFGOH	Pulled up through 10 kΩ internally	V _{CC1} - 0.5			V
Allowable output current	IFGOL				2	mA
[Lock Pin]						
High-level voltage	VLOH		2.5			V
Low-level voltage	VLOL				0.4	V
Input current	VLOIN	VLOCK = 3 V		25		μA
Leakage current	VLOLK	VLOCK = 0 V			-30	μA
[TSD]						
Thermal shutdown circuit (TSD) operating temperature	T-TSD	Design target value*		180		°C
TSD temperature hysteresis	ΔTSD	Design target value*		20		°C

*: Design target value parameters are not tested.



Truth Table

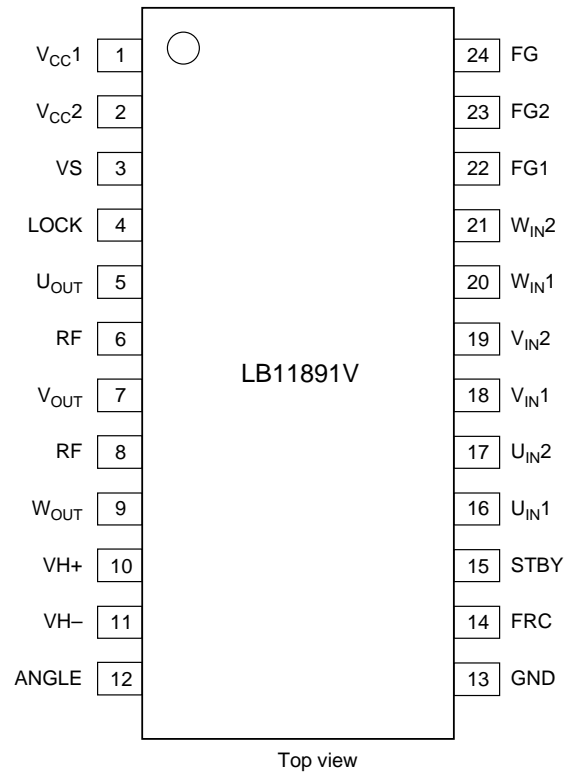
	Source → Sink	Hall inputs			FRC	LOCK
		U	V	W		
1	V → W	H	H	L	H	L
	W → V				L	
	V → U				H	H
	U → V				L	
2	U → W	H	L	L	H	L
	W → U				L	
	V → W				H	H
	W → V				L	
3	U → V	H	L	H	H	L
	V → U				L	
	U → W				H	H
	W → U				L	
4	W → V	L	L	H	H	L
	V → W				L	
	U → V				H	H
	V → U				L	
5	W → U	L	H	H	H	L
	U → W				L	
	W → V				H	H
	V → W				L	
6	V → U	L	H	L	H	L
	U → V				L	
	W → U				H	H
	U → W				L	

Note: The "H" entry in the FRC and LOCK columns indicates a voltage of 2.50 V or higher, and the "L" entry indicates a voltage of 0.4 V or lower. (When V_{CC1} is 3 V)

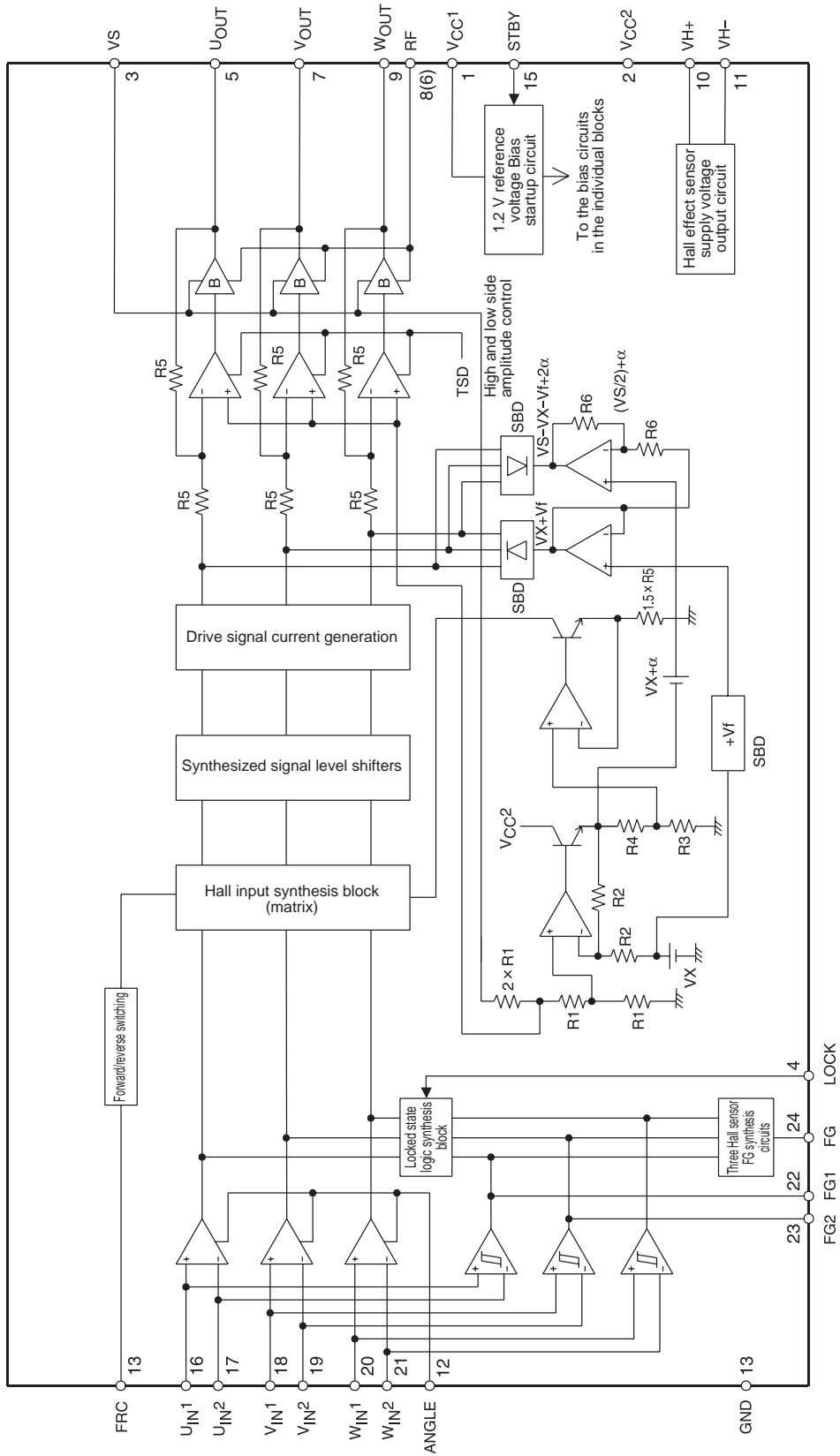
Note: For the Hall sensor inputs, the input "H" state is a state where the + input is at least 0.02 V higher than the - input, and the input "L" state is a state where the + input is at least 0.02 V lower than the - input.

LB11891V

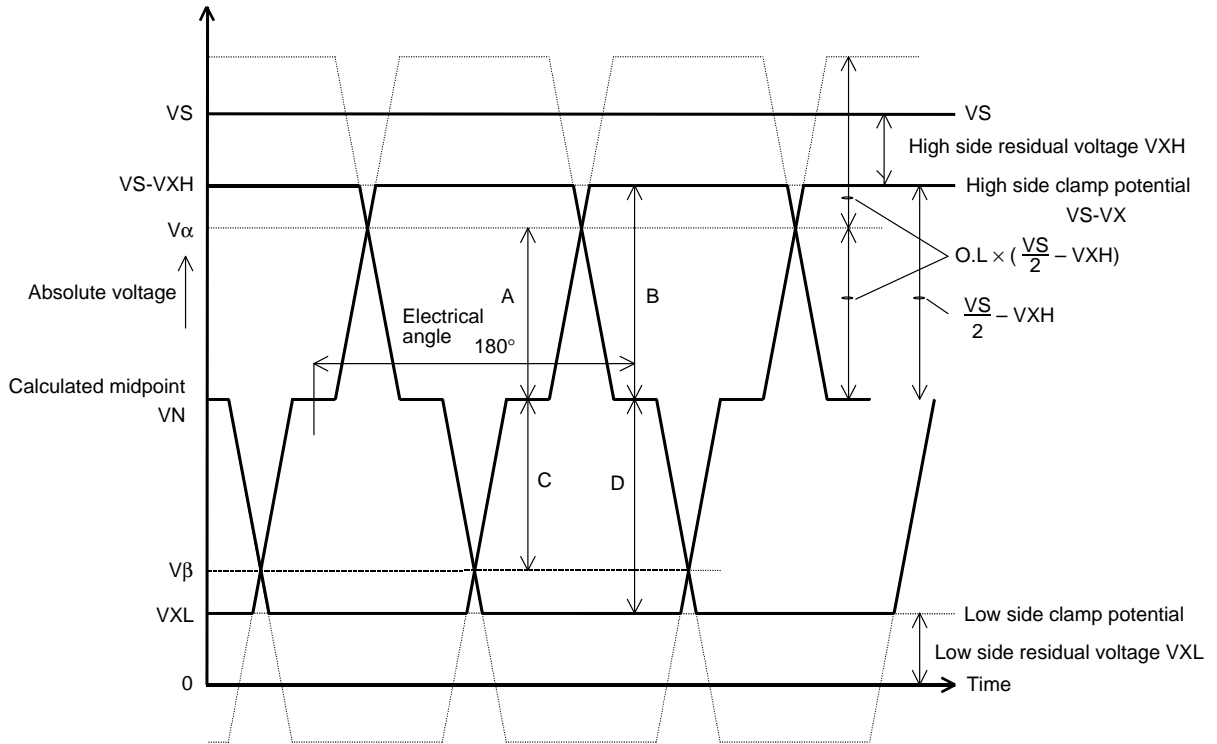
Pin Assignments



Block Diagram



Overlap Creation and Calculations



Overlap Creation

For the voltages generated in the control block, if the midpoint is taken as the reference, one side will be

$$2 \times \text{O.L.} \times \left(\frac{1}{2} \text{VS} - \text{VX} \right).$$

Therefore, the waveform crossover will be $\text{O.L.} \times \left(\frac{1}{2} \text{VS} - \text{VX} \right)$ from the midpoint.

Since that waveform is clamped at $\left(\frac{1}{2} \text{VS} - \text{VX} \right)$ referenced to the midpoint,

the overlap will be: $\frac{A}{B} \times 100 = \text{O.L.} \times 100$ [%].

Overlap Calculation

(1) High side overlap

The calculated midpoint is $\text{VN} = \frac{(\text{VS} - \text{VXH} - \text{VXL})}{2} + \text{VXL} = \frac{\text{VS} - \text{VXH} - \text{VXL}}{2}$

Since $A = \alpha - \text{VN}$ and $B = \text{VS} - \text{VXH} - \text{VN}$, the high side overlap can be calculated as follows.

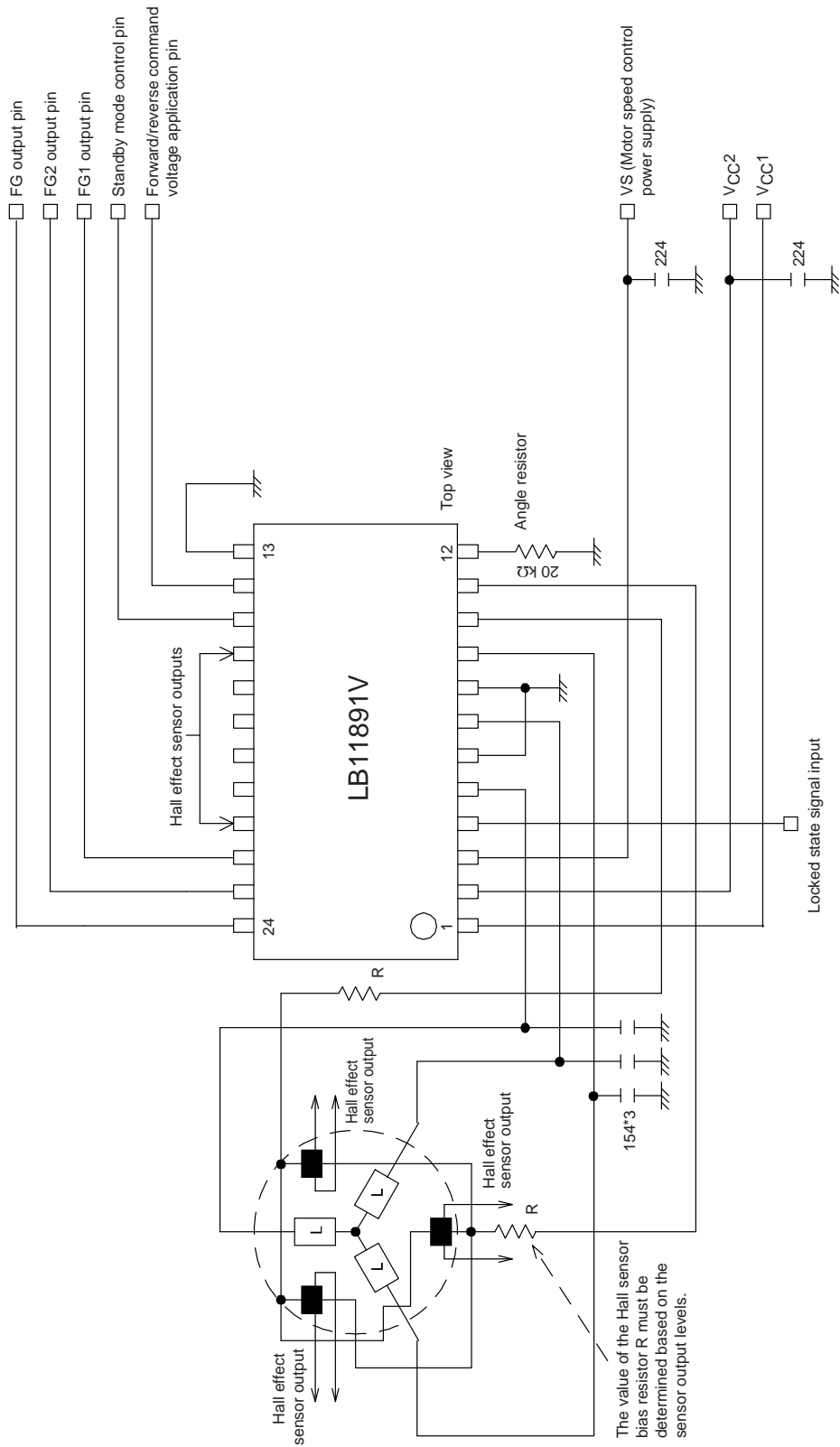
$$\text{Overlap} = \frac{A}{B} = \frac{\text{V}\alpha - ((\text{VS} - \text{VXH} + \text{VXL})/2)}{\text{VS} - \text{VXH} - ((\text{VS} - \text{VXH} + \text{VXL})/2)} \times 100 = \frac{2\text{V}\alpha - ((\text{VS} - \text{VXH}) - \text{VXL})}{(\text{VS} - \text{VXH} - \text{VXL})} \times 100$$
 [%].

(2) Low side overlap

Since $C = \text{VN} - \text{V}\beta$ and $D = \text{VN} - \text{VXL}$, the low side overlap can be calculated as follows.

$$\text{Overlap} = \frac{C}{D} = \frac{((\text{VS} - \text{VXH} + \text{VXL})/2) - \text{V}\beta}{((\text{VS} - \text{VXH} + \text{VXL})/2) - \text{VXL}} \times 100 = \frac{(\text{VS} - \text{VXH}) + \text{VXL} - 2\text{V}\beta}{(\text{VS} - \text{VXH}) - \text{VXL}} \times 100$$
 [%].

Application Circuit Example



Note: The component values shown in this application circuit example are examples only, and no guarantees, explicit or implicit, are made regarding their characteristics.

Pin Functions and Equivalent Circuits

Pin No.	Symbol	Voltage	Function	Equivalent circuit
16 17 18 19 20 21	U_{IN1} U_{IN2} V_{IN1} V_{IN2} W_{IN1} W_{IN2}	0 to V_{CC1}	Capstan motor driver U, V, and W phase Hall effect sensor inputs. The logic high state indicates that $IN1 > IN2$.	
12	ANGLE		Controls the gain from the Hall inputs to the output. The gain is controlled by the resistor inserted between this pin and ground.	
3	VS	0 to V_{CC2}	Power supply that determines the amplitude of the output to the capstan motor. This voltage must be lower than V_{CC2} .	
5 7 9 6, 8	U-OUT V-OUT W-OUT Rf		Capstan motor driver U, V, and W phase outputs.	
10 11	VH+ VH-		The Hall effect sensor element bias voltage supply. A voltage of 0.85 V (typical) is generated between the VH+ and VH- pins. (When I_H is 5 mA)	
22 23 24	FG1 FG2 FG		Comparator output for U_{IN1} and U_{IN2} . Comparator output for V_{IN1} and V_{IN2} . Three-phase synthesized output for the U, V, and W phase comparator output.	

Continued on next page.

LB11891V

Continued from preceding page.

Pin No.	Symbol	Voltage	Function	Equivalent circuit
14	FRC	0 to V _{CC1}	Capstan motor forward/reverse control. This pin determines the direction (forward or reverse) of the capstan motor. (This input has hysteresis characteristics.)	
15	STBY		Selects the bias supply for all the capstan motor circuits other than the FG comparator. Setting this pin low cuts off the bias supply. Thus it functions as the standby mode control pin.	
4	LOCK	0 to V _{CC1}	The output phase is locked by applying a low to high trigger voltage (edge) to this pin. This prevents the motor from turning due to the application of an external load in the motor stopped state.	
2	V _{CC2}	3.5 to 6 V	Power supply used for the source side pre-driver voltage and the coil waveform detection comparator.	
1	V _{CC1}	2.7 to 6 V	Power supply used for voltages other than the motor voltage, the source side pre-driver voltage, and the coil waveform detection comparator.	
13	GND		Ground used for all systems other than the output system.	

- Specifications of any and all SANYO products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Electric Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Electric Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of January, 2004. Specifications and information herein are subject to change without notice.